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**** FOREIGN APPLICATIONS *******

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35 USC 119(a-d) conditions met	<input checked="" type="checkbox"/> Yes <input type="checkbox"/> No		JAPAN	13	17	3
Verified and Acknowledged	/KEVIN QUINTO/ Examiner's Signature	Initials				

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TITLE

SEMICONDUCTOR MEMORY PREVENTING AN ELECTRIC SHORT CIRCUIT BETWEEN A WORD LINE AND A SEMICONDUCTOR SUBSTRATE, AND MANUFACTURING METHOD FOR THE SEMICONDUCTOR MEMORY

FILING FEE RECEIVED 1224	<p>FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:</p>	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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